

ICS 2200 REVISION QUESTIONS

- 1) What is the resistance of a nichrome wire 1mm in diameter and 1m in length? For nichrome, $\rho = 100 \times 10^{-8} \Omega\text{m}$ at 300K. (ANS 1.27Ω)
- 2) For an sinusoidal AC source delivering voltage v_s and current is:
 - a) Show that the average power dissipated for a purely resistive load is $V_{SRMS}I_{SRMS}$.
 - b) Show that the average power dissipated for a load with resistance and reactance is $V_{SRMS}I_{SRMS}\cos\phi$, where ϕ is the phase difference between voltage and current.
 - c) Show that the average power dissipated in a purely capacitive load is zero.
 - d) Show that the average power dissipated in a purely inductive load is zero.
- 3) An electric heater connected to a 240-V source consists of two identical $0.8\text{-}\Omega$ elements made of Nichrome wire. The elements provide low heat when connected in series and high heat when connected in parallel. Assuming the heater operates at a temperature of 300K, evaluate:
 - a) The length of wire in each heating element. (For nichrome, $\rho = 100 \times 10^{-8} \Omega\text{m}$ at 300K and $\alpha = 0.0004$ per $^\circ\text{C}$ at 20°C)
 - b) The power dissipated at low heat and high heat settings.
 - c) Repeat (a) and (b) for an operating temperature of 1500K.
- 4) A sine wave with amplitude 20V_{pp} is connected to a $10\text{ k}\Omega$ resistor. Calculate the peak, the rms, and the average currents through the resistor. What power rating should the resistor have to avoid damage?

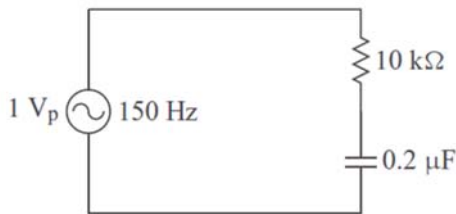


Figure Q5

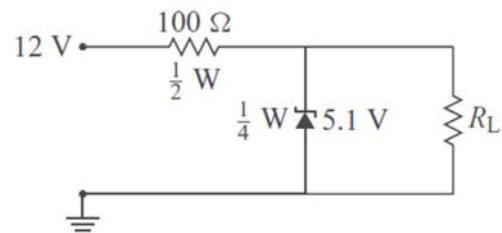


Figure Q8

- 5) Calculate the magnitude and the phase of the total impedance for the circuit in Figure Q5. (ANS magnitude $11.3\text{ k}\Omega$, phase -27.95 degrees)
- 6) Suppose we change the frequency of the signal generator in the circuit of Q5. If the angular frequency is set to 103 rad/s , what is the peak amplitude of the voltage across the capacitor? Of the voltage across the resistor?
- 7) Sketch the energy band configuration for a p-n junction under the following conditions: no bias, reverse bias, and forward bias. On each, indicate the direction of the net current.
- 8) In the circuit in Figure Q8, (Hint: think in terms of power ratings.)
 - a) What would happen if the load resistor were shorted? (ANS: If R_L is shorted, the power into the $\frac{1}{4}\text{W}$ resistor is 1.44W , so the resistor burns out)
 - b) What would happen if the load resistor were removed? Support your answers with calculations.

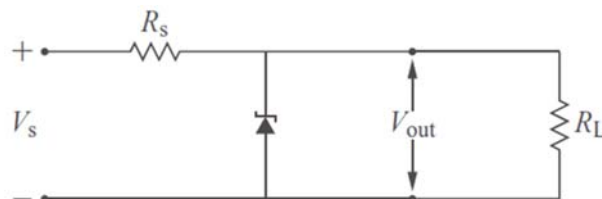


Figure Q9

- 9) In the Zener diode voltage regulator shown in circuit of Figure Q9:

- a) Determine the range of load resistances over which the circuit gives a constant V_{out} if $R_s = 1500\Omega$ and $V_s = 150\text{ V}$. Assume the diode breakdown voltage is 100 V and the maximum rated current is 100 mA . (ANS: Circuit gives a constant V_{out} for $R_L > 3\text{ k}\Omega$)
- b) If R_L is fixed at $10\text{ k}\Omega$, over what range of input voltages does the circuit regulate?
- 10) Let $V_s = 30\text{ V}$, $R_s = 300\Omega$, and the Zener breakdown voltage be 15 V in the circuit of Q9. Suppose we vary the load resistor R_L in order to vary the current through R_L (the load current). Plot the output voltage of the regulator as a function of load current from 0 to 75 mA . Over what load current range is the regulator effective?

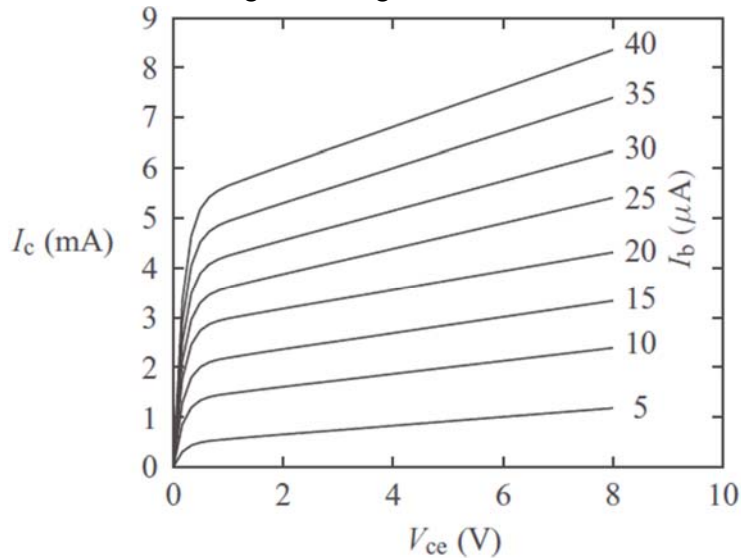


Figure Q11

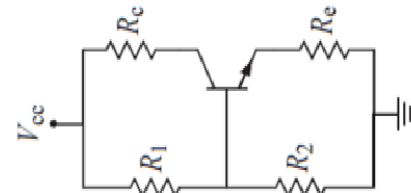


Figure Q12

- 11) Using the transistor characteristics in Figure Q11, find β for several values of I_B when $V_{CE} = 6\text{ V}$. Repeat for several values of V_{CE} when $I_B = 30\text{ }\mu\text{A}$. This shows that β is not really a constant over the linear active region.
- 12) Determine the operating point of the transistor DC bias circuit of Figure Q12 when $V_{CC} = 15\text{ V}$, $R_1 = 10\text{ k}\Omega$, $R_2 = 2.2\text{ k}\Omega$, $R_C = 680\text{ }\Omega$, and $R_E = 100\text{ }\Omega$. Assume $\beta = 200$ and $V_{BE} = 0.72\text{ V}$. (ANS: $I_B = 90.4\text{ }\mu\text{A}$, $I_C = 18.1\text{ mA}$, $V_{CE} = 0.873\text{ V}$)
- 13) Design a circuit that will set a reasonable operating point for a transistor with the characteristics of Figure Q11. Assume that the power rating for the transistor is 25 mW .

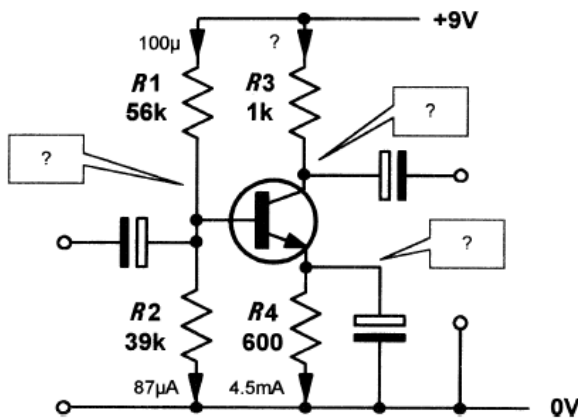


Figure Q14

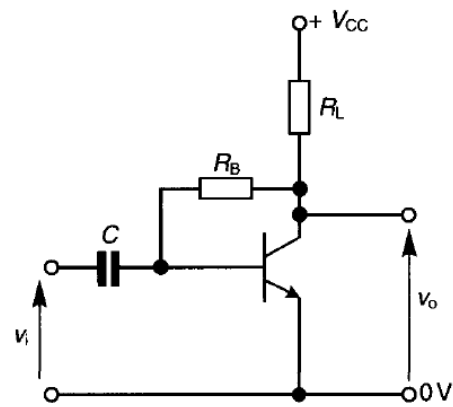


Figure Q15

- 14) Determine the unknown voltages and currents in the Figure Q14. (ANS: $13\text{ }\mu\text{A}$, 3.39 V , 2.7 V , 4.51 V)
- 15) For the BJT biasing circuit of Figure Q15 above:

- a) Calculate the resistor values for a collector operating current of 1mA, Collector voltage of 5V, supply voltage of 10V and $\beta = 100$.
- b) If the transistor is replaced by one with $\beta = 200$, confirm that the operating point will change to $V_{CE} = 3.3V$ and $I_C = 1.33mA$
- 16) Suppose an amplifier has an open-loop voltage gain of 20, an input impedance of $100\ \Omega$, and an output impedance of $50\ \Omega$. The amplifier is driven with a sinewave generator with output impedance of $50\ \Omega$ and an open loop amplitude of 0.1 Vpp. Find the resulting voltage across a $200\ \Omega$ load attached to the amplifier output. (ANS: 1.067 Vpp)

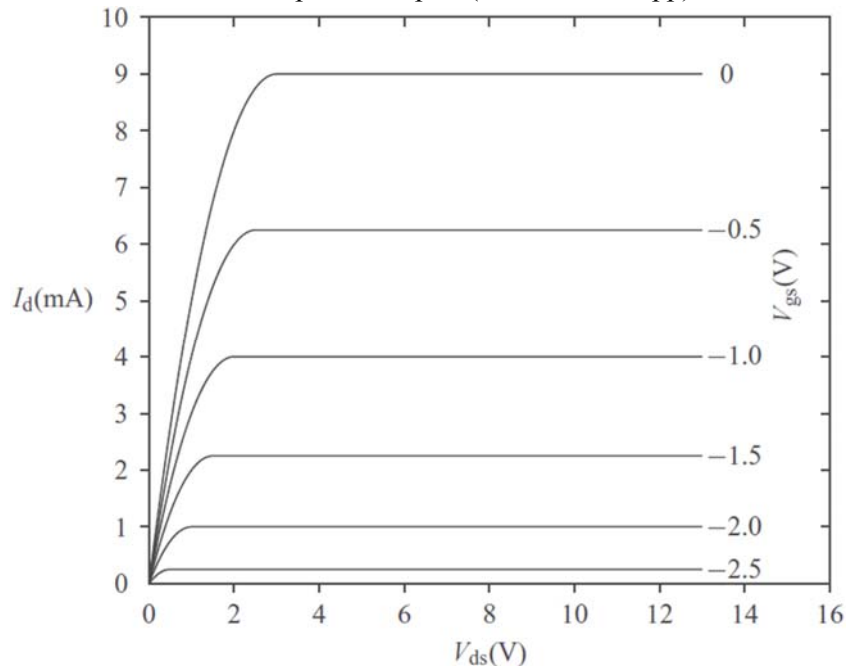


Figure Q17

- 17) Consider the transistor characteristics in Figure Q17. (ANS: $K = 1\text{ mA/V}^2$, $V_t = -3\text{ V}$)
- a) Are these the characteristics of a JFET, d-mosfet, or e-mosfet?
- b) Make a table of the given V_{gs} values and the corresponding $I_d(\text{sat})$ values. Also include a column in the table giving $\sqrt{I_d(\text{sat})}$.
- c) Make a plot of $\sqrt{I_d(\text{sat})}$ versus V_{gs} . Find the slope and y-intercept of the plot and use these to determine values for K and V_t in the model equation.

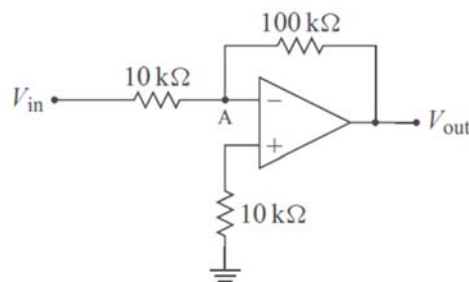


Figure Q18

- 18) For the circuit in Figure Q18, find V_{out} as a function of V_{in} and determine the input impedance of the circuit.
- 19) For each of the circuits in Figure Q19, determine the output voltage. Assume $\pm V_{sat} = \pm 10\text{ V}$.
- 20) Draw the schematic diagram of an inverting amplifier with $R_i = 5\text{ k}\Omega$ and a voltage gain of -75 .

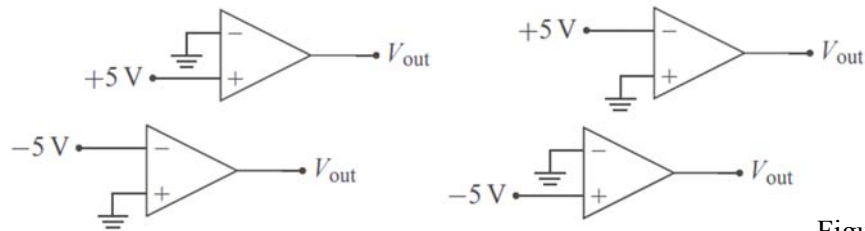


Figure Q19

21) If the circuit of Q20 uses $\pm 12\text{ V}$ power supplies, what input voltage will cause the output to saturate? (ANS: 147 mV)

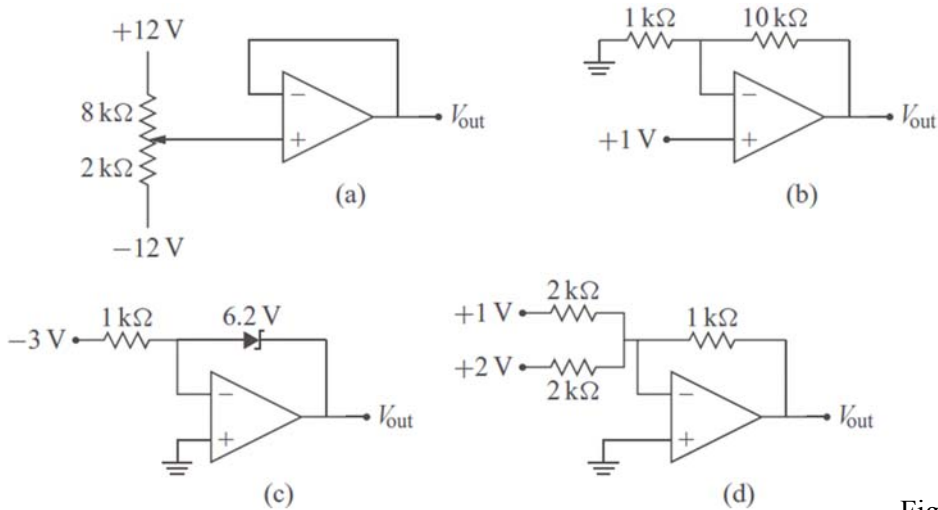


Figure Q22

22) Determine the output voltage for each circuits in Figure Q22. (ANS(a): $V_{out} = -7.2\text{ V}$)

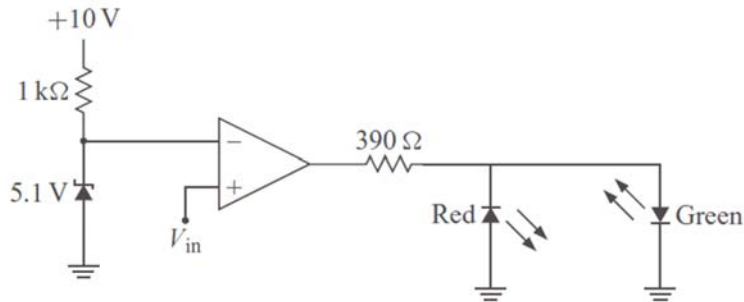


Figure Q23

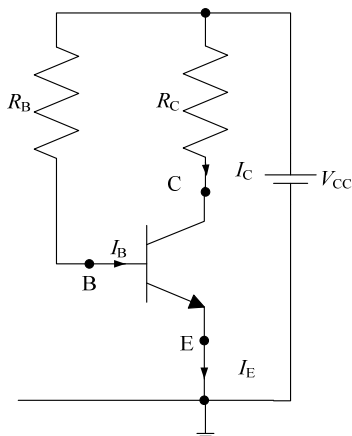


Figure Q25

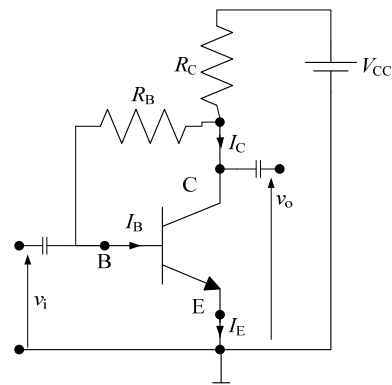


Figure Q26

23) Explain the operation of the circuit in Figure Q23 as V_{in} is varied.

24) For the circuit of Figure Q12, $V_{CC} = 12\text{ V}$, $R_1 = 60\text{k}\Omega$, $R_2 = 12\text{k}\Omega$, $R_C = 15\text{k}\Omega$ and $R_E = 10\text{k}\Omega$. Assume $\beta = 50$ and $V_{BE} = 0.6\text{ V}$.

- a) Determine the quiescent values of I_C and V_{CE} . (0.135mA, 8.6V).
 b) Repeat (a) if $\beta = 20$. (0.127mA, 8.76V).
 c) Repeat (a) if $\beta = 125$. (0.138mA, 8.54V).
- 25) For the circuit of Figure Q25, $V_{CC} = 60V$, $R_B = 6k\Omega$, and $R_C = 30\Omega$. Assume $V_{BE} = 0.7V$.
 a) What is the value of β if the quiescent values of $I_C = 1.15A$ and $V_{CE} = 25V$. (116?).
 b) What is the power dissipated in the transistor?
 c) What is the total power supplied by V_{CC} ? (69.6W)
 d) What will be the quiescent values if $V_{CC} = 50V$, $R_B = 8k\Omega$, and $R_C = 20\Omega$.
- 26) For the circuit in Figure Q26, $V_{CC} = 9V$, $\beta = 100$ and $V_{BE} = 0.6V$. The operating point has $I_C = 5mA$ and $V_{CE} = 5V$ [10 Marks]
 a) Explain the purpose of the capacitors connected at v_i and v_o .
 b) Determine the values of resistors R_B and R_C .
 c) Determine the values of resistors R_B and R_C if the transistor has $\beta = 50$.

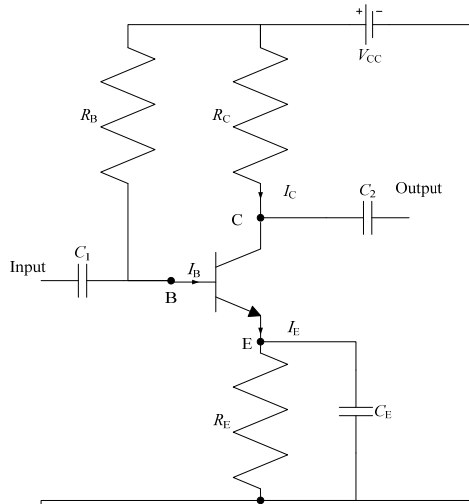
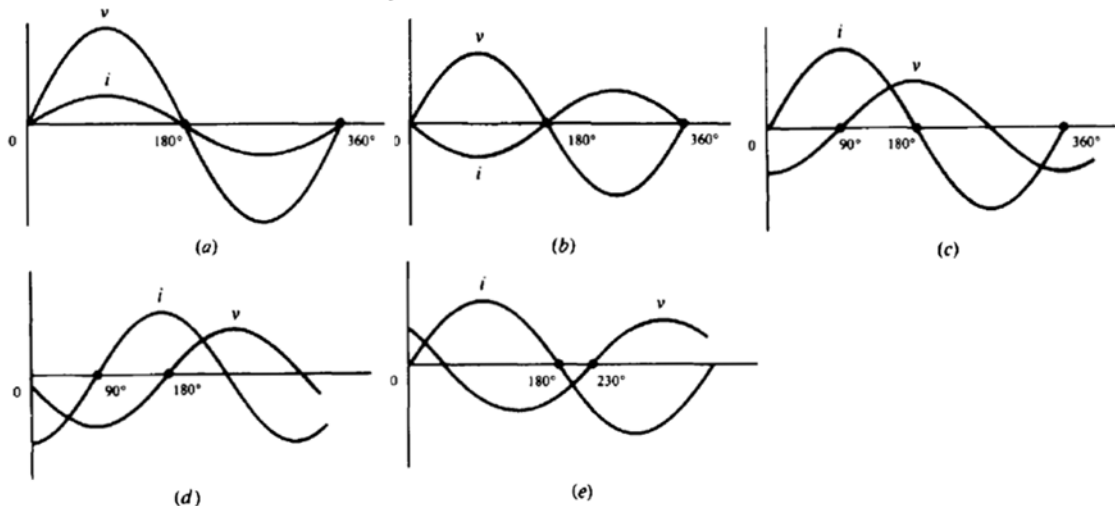


Figure Q27

- 27) For the circuit in Figure Q27, $V_{CC} = 15V$, $R_B = 280k\Omega$, $R_C = 1k\Omega$, $R_E = 2k\Omega$, $\beta = 100$ and $V_{BE} = 0.6V$. [10 Marks]
 a) Explain the purpose of the capacitors C_1 , C_2 and C_E .
 b) Determine the quiescent values of I_C and V_{CE} .
 c) Determine the quiescent values if the transistor has $\beta = 200$.

Revision Questions Alternating Current:



- For the waveforms below, indicate the phase angle (in degrees and radians) between the voltage and current. Indicate which quantity is leading and which is lagging.
- A 4Ω heater is connected to the 240V ac power source by two 50m lengths of copper wire of cross-sectional area 1.5mm^2 . The resistivity of copper is $1.68 \times 10^{-8}\Omega\cdot\text{m}$. Sketch the circuit and calculate the following:
 - The total length of wire that connects the 8Ω heater to the 240Vac power source.
 - The resistance of the connecting wires and the total resistance, R_T , of the circuit.
 - The current, I , in the circuit.
 - The voltage drop across each 50m length of copper wire.
 - The voltage across the 8Ω heater.
 - The I^2R power loss in each 50m length of copper wire.
 - The power dissipated by the 8Ω heater.
 - The total power, P_T , supplied to the circuit by the 240Vac power line.
 - The percentage of the total power, P_T , dissipated by the 8Ω heater.
- Recalculate the values in steps a through to i if the 1.5mm^2 wires are replaced by 2.5mm^2 .
- Recalculate the values in steps a through to i if the 8Ω heater is replaced with a 24Ω fan.
- The peak voltage of an ac sine wave is 100 V. (a) Find the instantaneous voltage at 0,30,60,90, 135, and 245°. (b) Express the angles in radians (in terms of π). (c) Plot these points and draw the sine wave voltage.
- If an ac voltage wave has an instantaneous value of 90V at $\pi/6$ radians, find the peak value.
- An ac wave has an RMS value of 50mA. Find the peak value and the instantaneous value at $\pi/3$ radians

Revision Questions – Conduction in Semiconductors:

- What are two other names for depletion zone?
- Can a silicon diode be forward-biased if the anode voltage is negative? Explain your answer.
- Explain why a bridge rectifier would be used instead of a two-diode full-wave rectifier.
- Explain why the Zener current and load current variations in a loaded Zener regulator are equal but opposite.

- 5) Explain the following terms for a P-N diode: (a) Forward bias; (b) Reverse bias.
- 6) Explain the process of: (a) Zener breakdown; (b) Avalanche breakdown.
- 7) Which type of breakdown is applied deliberately in an electronic device?

Revision Questions Op Amps:

- 1) What is a common-mode signal?
- 2) What is the common-mode rejection ratio and how is it usually specified?
- 3) What are the advantages of using negative feedback with an amplifier?
- 4) Explain the concept called virtual ground.
- 5) Why is a Schmitt trigger immune to erratic triggering caused by noise?
- 6) Draw the block diagram of operational amplifier, labelling all the terminals.
- 7) For an amplifier, explain the terms: (a) input impedance; (b) output impedance; (c) Voltage gain.
- 8) For the inverting amplifier given that $R_1=1\text{k}\Omega$ and $R_F=10\text{k}\Omega$. Assuming an ideal op amp, calculate the output voltage for the input of 1V.
- 9) For the non-inverting amplifier given that $R_1=1\text{k}\Omega$ and $R_F=10\text{k}\Omega$. Assuming an ideal op amp, calculate the output voltage for the input of 1V.
- 10) Sketch the circuit of op amp: (a) Inverting amplifier; (b) Non-inverting amplifier; (c) Inverting summer with 3 inputs.
- 11) Derive the expression for voltage gain for op amp: (a) Inverting amplifier; (b) Non-inverting amplifier; (c) Inverting summer with 3 inputs.
- 12) Sketch the circuit and explain the working of a precision rectifier.
- 13) What are the possible applications of comparators and Schmitt triggers? Why would a Schmitt trigger be preferred to a comparator?
- 14) For a Schmitt trigger, explain the term hysteresis or 'dead zone'.